

FZT788BTC Datasheet

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| | |
|------------------------------|--|
| DiGi Electronics Part Number | FZT788BTC-DG |
| Manufacturer | Diodes Incorporated |
| Manufacturer Product Number | FZT788BTC |
| Description | TRANS PNP 15V 3A SOT223-3 |
| Detailed Description | Bipolar (BJT) Transistor PNP 15 V 3 A 100MHz 2 W S urface Mount SOT-223-3 |



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Purchase and inquiry

Manufacturer Product Number:

FZT788BTC

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

15 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

2 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-261-4, TO-261AA

Base Product Number:

FZT788

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

500mV @ 50mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

500 @ 10mA, 2V

Frequency - Transition:

100MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-223-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Affected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

15V PNP MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

Features

- $BV_{CEO} > -15V$
- $BV_{CBO} > -15V$
- $I_C = -3A$ High Continuous Current
- $h_{FE} > 300$ @ $-2A$ and Low Saturation Voltage
- Extremely Low Equivalent On-Resistance $R_{CE(sat)}$ 93m Ω at $-3A$
- Complementary NPN Type: DIODES™ FZT688B
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

Mechanical Data

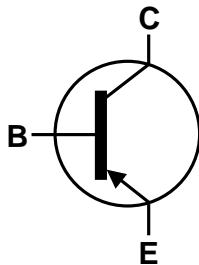
- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)

Applications

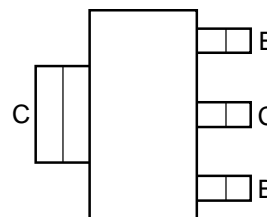
- Flash Gun Convertors
- Battery Powered Circuits



Top View



Device Symbol



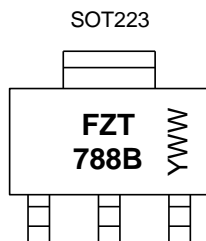
Top View Pin-Out

Ordering Information (Note 4)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------|------------|---------|--------------------|-----------------|-------------------|
| FZT788BTA | Standard | FZT788B | 7 | 12 | 1,000 |
| FZT788BTC | Standard | FZT788B | 13 | 12 | 2,500 |

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



FZT 788B = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or \bar{WW} = Week Code (01~53)



FZT788B

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -15 | V |
| Collector-Emitter Voltage | V _{CEO} | -15 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | I _C | -3 | A |
| Peak Pulse Current | I _{CM} | -8 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Power Dissipation | P _D | (Note 5) | 3 |
| | | (Note 6) | 2 |
| | | (Note 7) | 1.6 |
| | | (Note 8) | 1.2 |
| Thermal Resistance, Junction to Ambient | R _{θJA} | (Note 5) | 41.7 |
| | | (Note 6) | 62.5 |
| | | (Note 7) | 78.1 |
| | | (Note 8) | 104 |
| Thermal Resistance Junction to Lead | R _{θJL} | 12.9 | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 10)

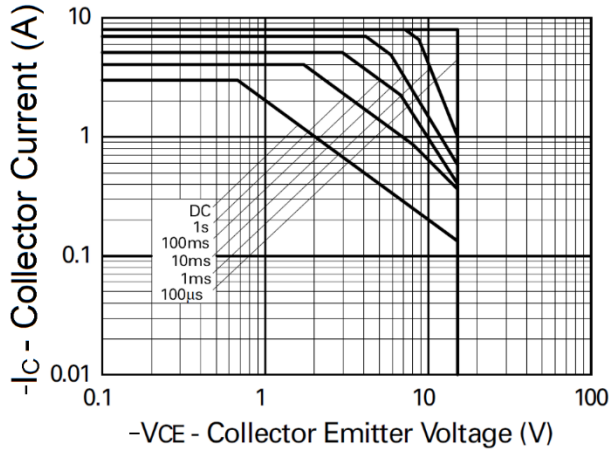
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

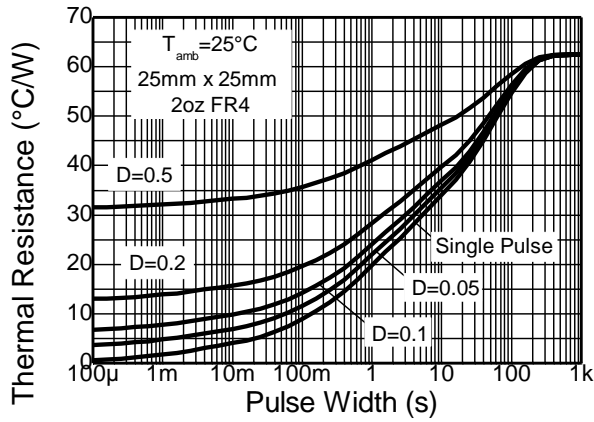


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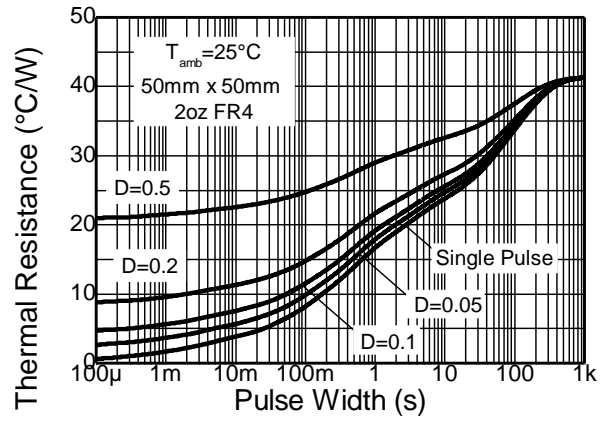
Thermal Characteristics and Derating Information



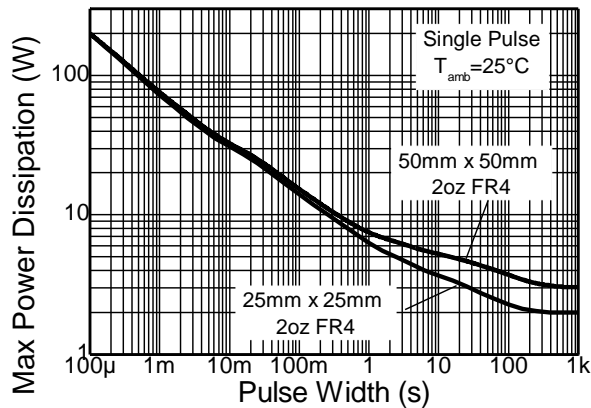
Safe Operating Area



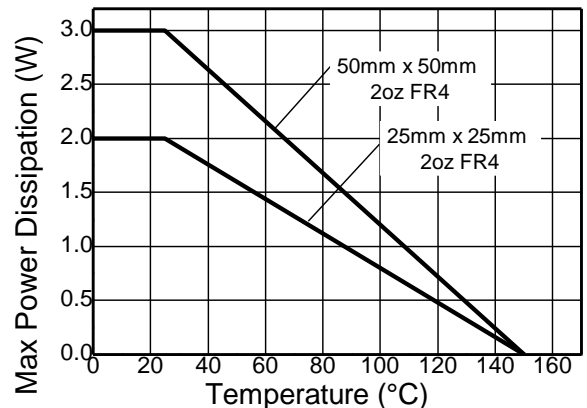
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



FZT788B

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

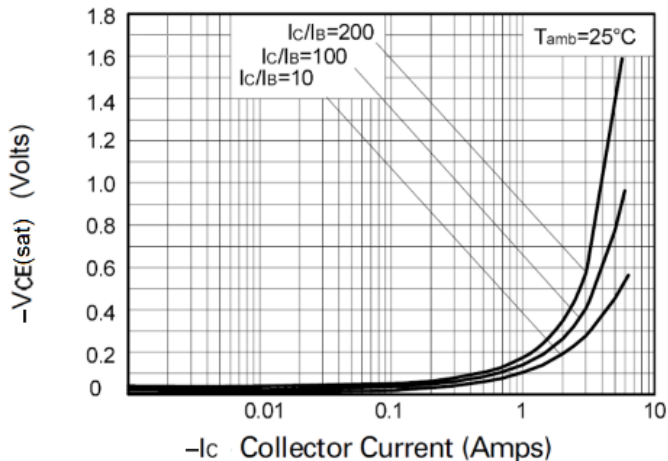
| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|---------------|--------------------------|------------------|---------------------------------|------|--|
| Collector-Base Breakdown Voltage | BV_{CBO} | -15 | — | — | V | $I_C = -100\mu A$ |
| Collector-Emitter Breakdown Voltage (Note 11) | BV_{CEO} | -15 | — | — | V | $I_C = -10mA$ |
| Emitter-Base Breakdown Voltage | BV_{EBO} | -7 | — | — | V | $I_E = -100\mu A$ |
| Collector-Base Cut-Off Current | I_{CBO} | — | — | -100 | nA | $V_{CB} = -10V$ |
| Emitter Cut-Off Current | I_{EBO} | — | — | -100 | nA | $V_{EB} = -4V$ |
| DC Current Gain (Note 11) | h_{FE} | 500 400 300 150 | — — — — | — — — — | — | $I_C = -10mA, V_{CE} = -2V$ $I_C = -1A, V_{CE} = -2V$ $I_C = -2A, V_{CE} = -2V$ $I_C = -6A, V_{CE} = -2V$ |
| Collector-Emitter Saturation Voltage (Note 11) | $V_{CE(sat)}$ | — — — — | — — — — | -0.15 -0.25 -0.45 -0.5 | V | $I_C = -0.5A, I_B = -2.5mA$ $I_C = -1A, I_B = -5mA$ $I_C = -2A, I_B = -10mA$ $I_C = -3A, I_B = -50mA$ |
| Base-Emitter Saturation Voltage (Note 11) | $V_{BE(sat)}$ | — | — | -0.9 | V | $I_C = -1A, I_B = -5mA$ |
| Base-Emitter Turn-On Voltage (Note 11) | $V_{BE(on)}$ | — | -0.75 | — | V | $I_C = -1A, V_{CE} = -2V$ |
| Input Capacitance | C_{ibo} | — | 225 | — | pF | $V_{EB} = -0.5V, f = 1MHz$ |
| Output Capacitance | C_{obo} | — | 25 | — | pF | $V_{CB} = -10V, f = 1MHz$ |
| Current Gain-Bandwidth Product | f_T | 100 | — | — | MHz | $V_{CE} = -5V, I_C = -50mA, f = 50MHz$ |
| Turn-On Time | t_{on} | — | 35 | — | ns | $V_{CC} = -10V, I_C = -500mA$ |
| Turn-Off Time | t_{off} | — | 400 | — | ns | $I_{B1} = -I_{B2} = -50mA$ |

Note: 11. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.

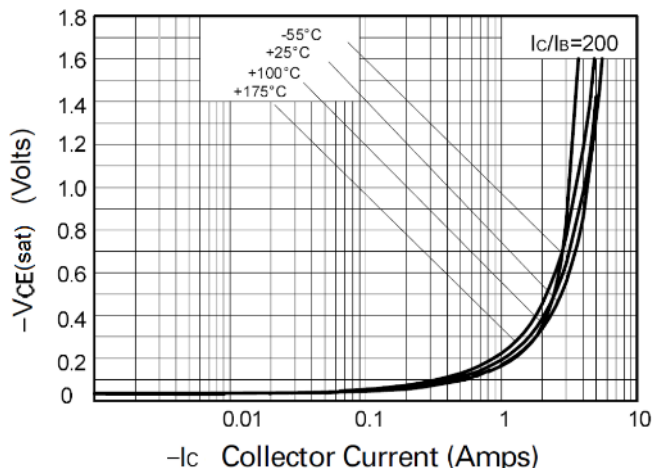


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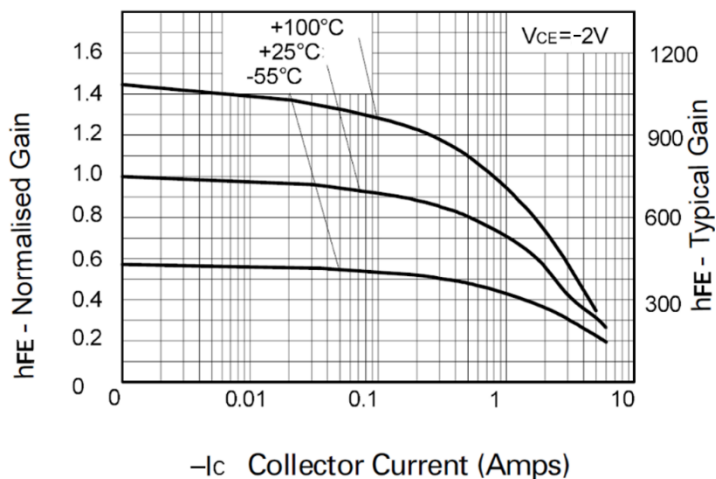
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



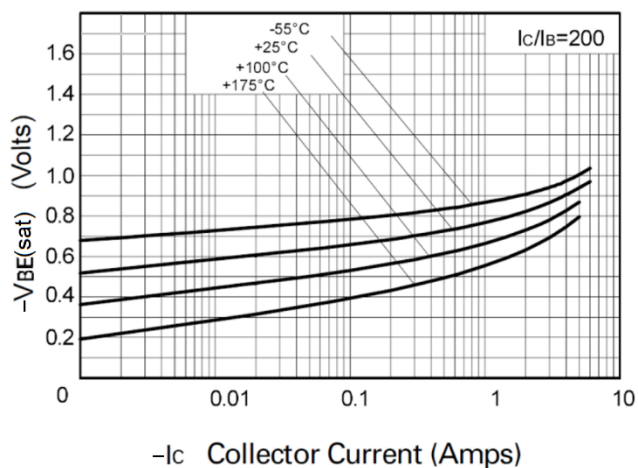
VCE(sat) v IC



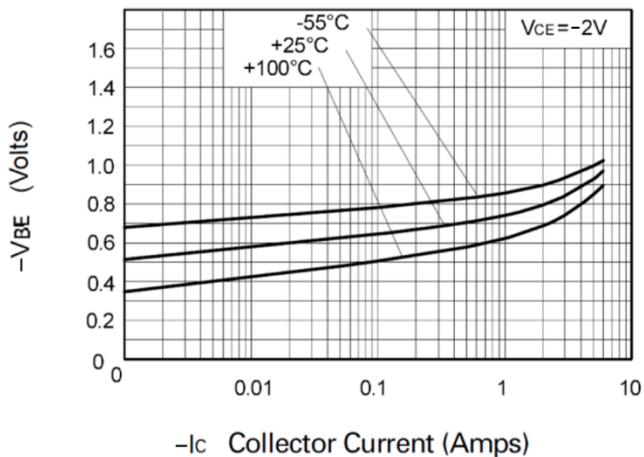
VCE(sat) v IC



hFE v IC



VBE(sat) v IC



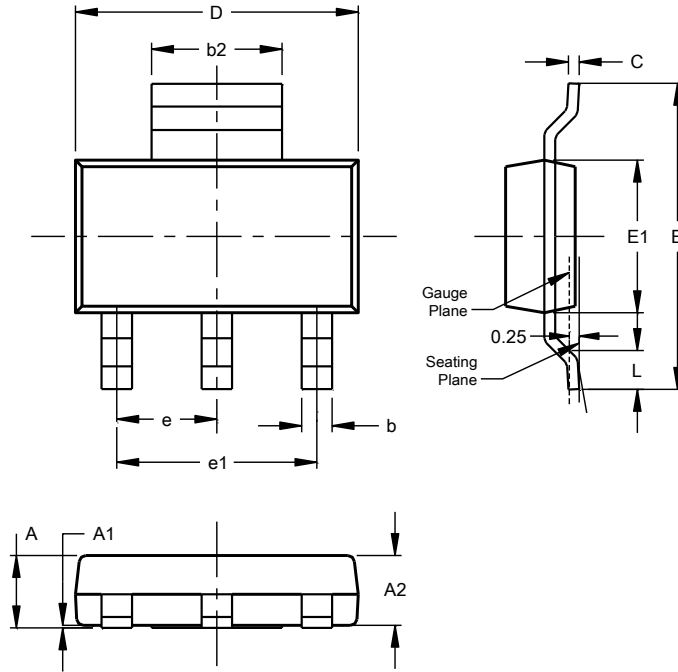
VBE(on) v IC



FZT788B

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

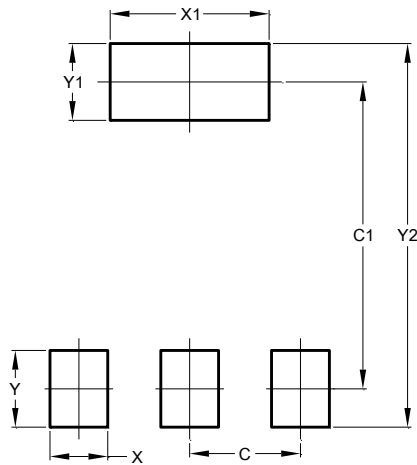


| SOT223 (Type DN) | | | |
|----------------------|------|------|------|
| Dim | Min | Max | Typ |
| A | -- | 1.70 | -- |
| A1 | 0.01 | 0.15 | -- |
| A2 | 1.50 | 1.68 | 1.60 |
| b | 0.60 | 0.80 | 0.70 |
| b2 | 2.90 | 3.10 | -- |
| c | 0.20 | 0.32 | -- |
| D | 6.30 | 6.70 | -- |
| E | 6.70 | 7.30 | -- |
| E1 | 3.30 | 3.70 | -- |
| e | -- | -- | 2.30 |
| e1 | -- | -- | 4.60 |
| L | 0.85 | -- | -- |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 2.30 |
| C1 | 6.40 |
| X | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |



FZT788B

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